TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC20AP,TC74HC20AF,TC74HC20AFN

Dual 4-Input NAND Gate

The TC74HC20A is a high speed CMOS 4-INPUT NAND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

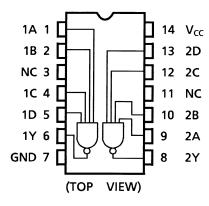
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

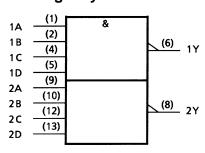
Features

- High speed: $t_{pd} = 8 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: ICC = 1 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: | IOH | = IOL = 4 mA (min)
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS20

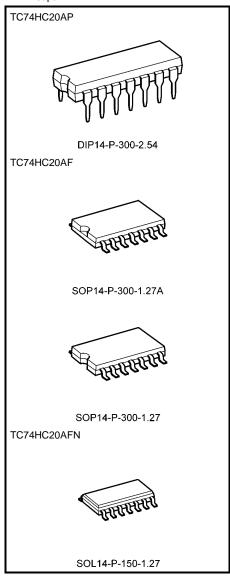
Pin Assignment



IEC Logic Symbol



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 DIP14-P-300-2.54
 : 0.96 g (typ.)

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)



Truth Table

Α	В	С	D	Υ
L	Χ	Х	Х	Н
Х	L	Х	Х	Н
Х	Х	L	Х	Н
Х	Х	Х	L	Н
Н	Н	Н	Н	L

X: Don't care

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	٧
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition V _{CC}			Ta = 25°C			Ta = -40 to 85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
ŭ				6.0	4.20	_	_	4.20	_	
		_		2.0		_	0.50	_	0.50	
Low-level input voltage	V_{IL}			4.5	_	_	1.35		1.35	V
Ŭ				6.0			1.80	_	1.80	
	Voн	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20~\mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0		5.9	—	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31		4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80		5.63	—	
	V _{OL}	V _{IN} = V _{IH}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \ \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
Ŭ			$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0			±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	_	_	1.0	_	10.0	μА

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition		Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	5	8	ns
Propagation delay time	t _{pLH}	_	_	8	15	ns



AC Characteristics (C_L = 50 pF, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Output transition time			2.0	_	30	75	_	95	
	t _{TLH}	_	4.5	_	8	15	_	19	ns
	tTHL		6.0	_	7	13	_	16	
Propagation delay time	t _p LH t _p HL		2.0	_	33	90	_	115	
		1	4.5	_	11	18	_	23	ns
			6.0	_	9	15	_	20	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	29	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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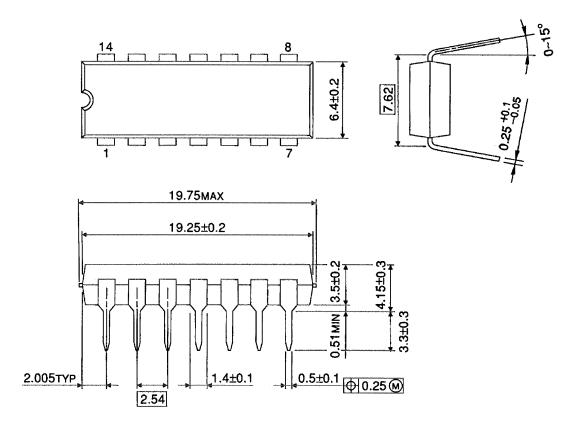
Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per gate)



Package Dimensions

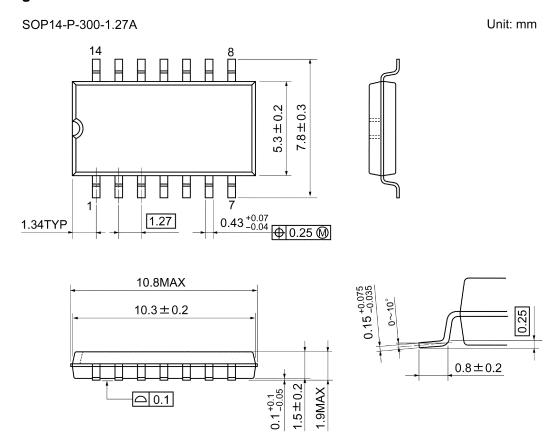
DIP14-P-300-2.54 Unit: mm



Weight: 0.96 g (typ.)



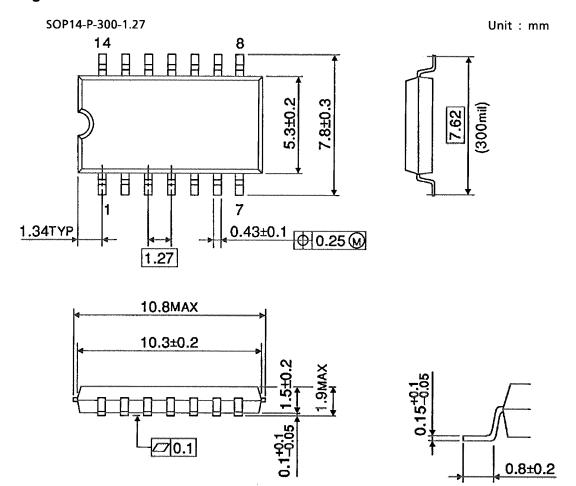
Package Dimensions



Weight: 0.18 g (typ.)



Package Dimensions

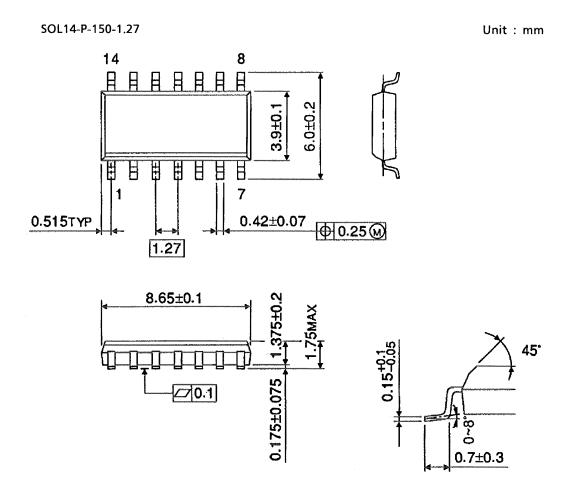


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Weight: 0.18 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27

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